

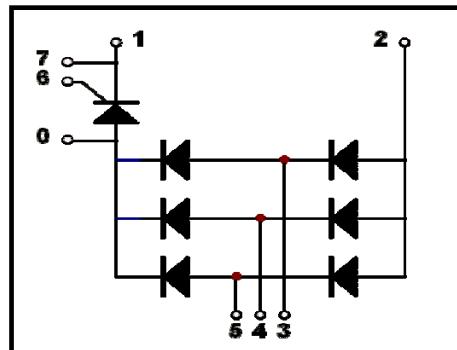
## Features

- Isolated Module Package
- Isolation voltage 3000 V
- Three Phase Bridge and a Thyristor



## Applications

- Current Stabilized Power Supply
- Switching Power Supply
- Inverter For AC or DC Motor Control



### ■ Diode

## ABSOLUTE MAXIMUM RATINGS

 $T_C=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Max.	Unit
$V_{RRM}$	Repetitive Reverse Voltage		1600	V
$I_{D(AV)}$	Average Forward Current	$T_C=90^\circ\text{C}$ , moudle	100	A
$I_{FSM}$	Non-Repetitive Surge Forward Current	$T_J=45^\circ\text{C}$ , $t=10\text{ms}$ , 50Hz, Sine	1200	A
		$T_J=45^\circ\text{C}$ , $t=8.3\text{ms}$ , 60Hz, Sine	1300	A
$I^2t$	$I^2t$ (For Fusing)	$T_J=45^\circ\text{C}$ , $t=10\text{ms}$ , 50Hz, Sine	7.2	$\text{KA}^2\text{s}$
		$T_J=45^\circ\text{C}$ , $t=8.3\text{ms}$ , 60Hz, Sine	8.4	$\text{KA}^2\text{s}$
$T_J$	Junction Temperature		-40~150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range		-40~125	$^\circ\text{C}$
$V_{isol}$	Insulation Test Voltage	50Hz, all terminals shorted, $t=5\text{s}$ , $I_{ISOL}\leq 1\text{mA}$ ;	3500	V
Weight			215	g

## ELECTRICAL AND THERMAL CHARACTERISTICS

 $T_C=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{RM}$	Reverse Leakage Current	$V_R=1600\text{V}$	--	--	500	$\mu\text{A}$
		$V_R=1600\text{V}$ , $T_J=125^\circ\text{C}$	--	--	4	mA
$V_F$	Forward Voltage	$I_F=100\text{A}$	--	1.15	1.4	V
		$I_F=100\text{A}$ , $T_J=125^\circ\text{C}$	--	1.1	--	V
$R_{\theta JC}$	Thermal Resistance Junction-to-Case	per diode	--	--	0.9	$^\circ\text{C}/\text{W}$
		per module	--	--	0.15	$^\circ\text{C}/\text{W}$
$R_{\theta CS}$	Thermal Resistance Case -to-Sink	per diode	--	--	0.42	$^\circ\text{C}/\text{W}$
		per module	--	--	0.07	$^\circ\text{C}/\text{W}$

## ■ Thyristor

## ABSOLUTE MAXIMUM RATINGS

 $T_C=25^\circ\text{C}$  unless otherwise specified

Symbol	Test Condition	Value	Unit
$V_{RRM}$		1600	V
$I_{T(AV)}$	$T_C=90^\circ\text{C}$ , 180° conduction, half sine wave;	100	A
$I_{TSM}$	$T_J=45^\circ\text{C}$ , $t=10\text{ms}$ (50Hz), sine, $V_R=V_{RRM}$ ;	1500	A
	$T_J=45^\circ\text{C}$ , $t=8.3 \text{ ms}$ (60Hz), sine, $V_R=V_{RRM}$ ;	1650	
$I^2t$	$T_J=45^\circ\text{C}$ , $t=10\text{ms}$ (50Hz), sine, $V_R=V_{RRM}$ ;	9.1	$\text{KA}^2\text{s}$
	$T_J=45^\circ\text{C}$ , $t=8.3 \text{ ms}$ (60Hz), sine, $V_R=V_{RRM}$ ;	9.8	
$dv/dt$	$T_J=125^\circ\text{C}$ , linear to $0.67V_{DRM}$	1000	V/us
$di/dt$	$T_J=125^\circ\text{C}$ , $I_{TM}=314\text{A}$ , from $0.67V_{DRM}$	150	A/us
$V_{ISOL}$	50Hz, all terminals shorted, $t=5\text{s}$ , $I_{ISOL}\leq 1\text{mA}$ ;	3500	V~
$T_J$	Max. junction operating temperature range	-40~125	°C
$T_{STG}$	Max. storage temperature range	-40~125	°C
	Mounting torque(M6)	3 to 5	N·m
	Terminal connection torque(M6)	3 to 5	N·m
	Terminal connection torque(M4)	1 to 2	N·m

## ELECTRICAL AND THERMAL CHARACTERISTICS

 $T_C=25^\circ\text{C}$  unless otherwise specified

Symbol	Test Condition	Min.	Typ.	Max.	Unit
$I_{DRM}/I_{RRM}$	$V_D=V_R=1600\text{V}$ ;			500	μA
$I_{DRM}/I_{RRM}$	$T_J=125^\circ\text{C}$ , $V_D=V_R=1600\text{V}$ ;			21	mA
$V_{TM}$	$I_{TM}=150\text{A}$ , $t_d=10 \text{ ms}$ , half sine;			1.5	V
$V_{GT}$	$V_A=6\text{V}$ , $R_A=1\Omega$ , $T_j=-40^\circ\text{C}$ ;			4	V
	$V_A=6\text{V}$ , $R_A=1\Omega$ ;			3.2	
	$V_A=6\text{V}$ , $R_A=1\Omega$ , $T_j=125^\circ\text{C}$ ;			1.7	
$I_{GT}$	$V_A=6\text{V}$ , $R_A=1\Omega$ , $T_j=-40^\circ\text{C}$ ;			270	mA
	$V_A=6\text{V}$ , $R_A=1\Omega$ ;			140	
	$V_A=6\text{V}$ , $R_A=1\Omega$ , $T_j=125^\circ\text{C}$ ;			80	
$P_{GM}$	$t\leq 5\text{ms}$ , $T_j=125^\circ\text{C}$ ;			12	W
$P_{GM(AV)}$	$f=50\text{Hz}$ , $T_j=125^\circ\text{C}$ ;			3	W
$R_{thjc}$	Thermal Resistance , Junction-to-Case			0.3	K/W
$R_{THCS}$	Thermal Resistance, Case -to-Sink			0.07	K/W

### Characteristic curves

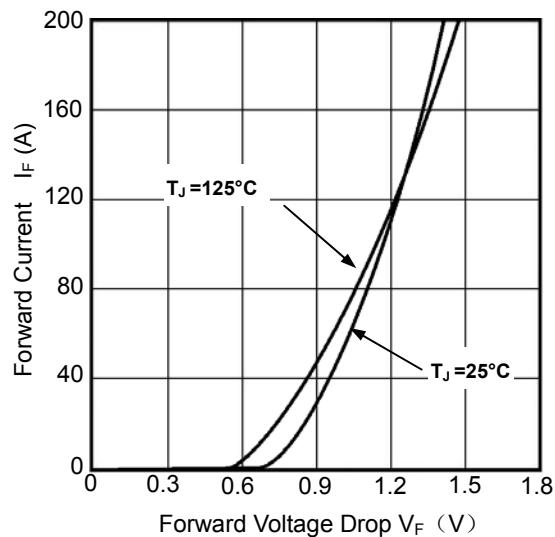


Figure 1. Diode Forward Voltage Drop vs Forward Current

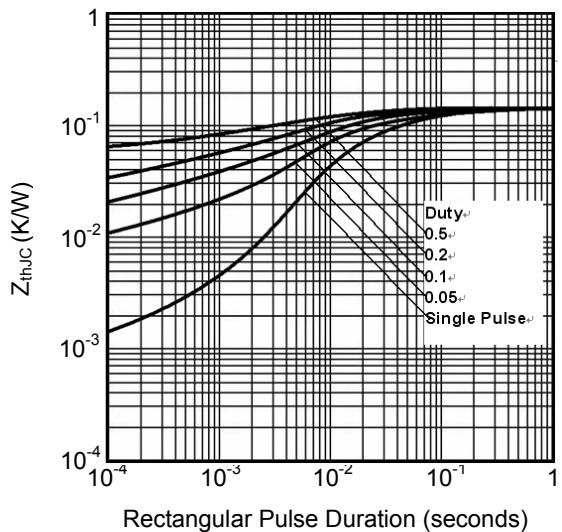
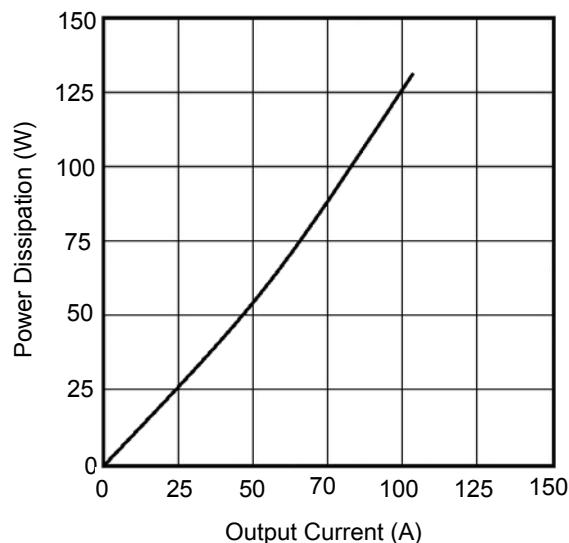
Figure 2. Diode Thermal Impedance Z<sub>thJC</sub>

Figure 3. SCR Output Current vs Power Dissipation

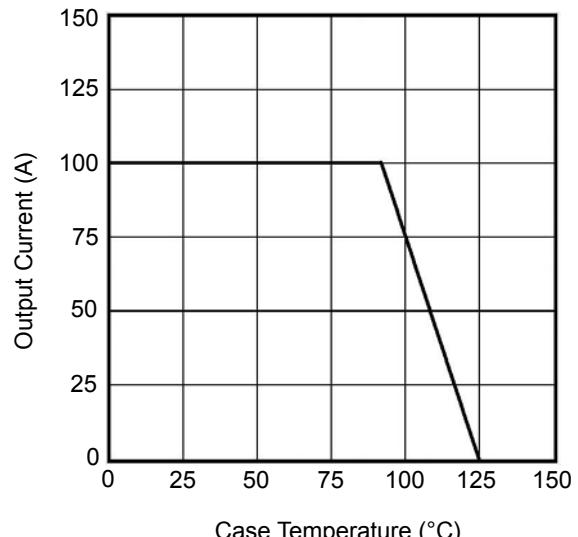


Figure 4. SCR Output Current vs Case Temperature

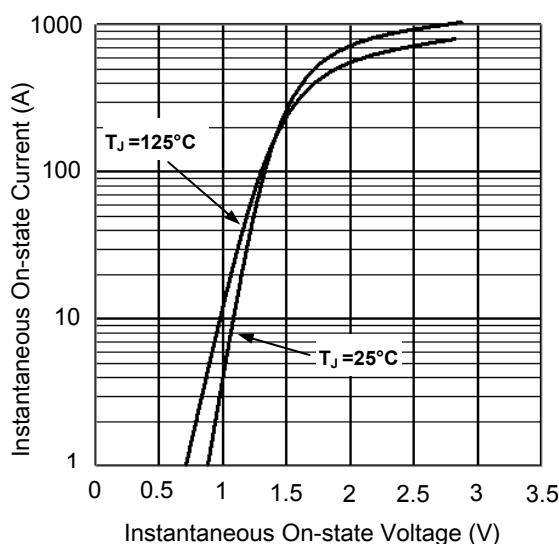
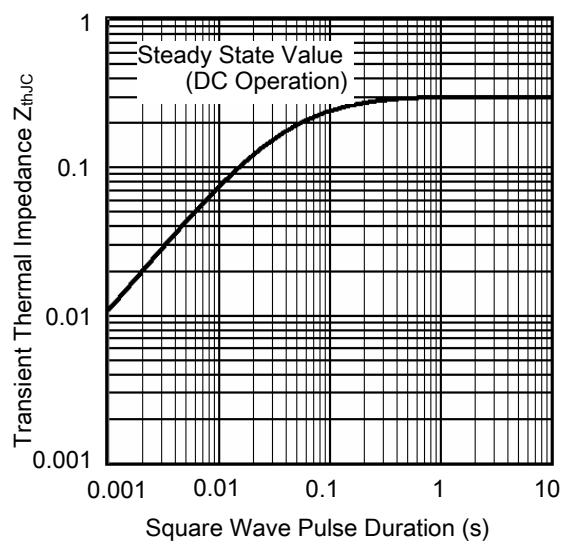


Figure 5. SCR On State Voltage Drop

Figure 6. SCR Thermal Impedance Z<sub>thJC</sub>

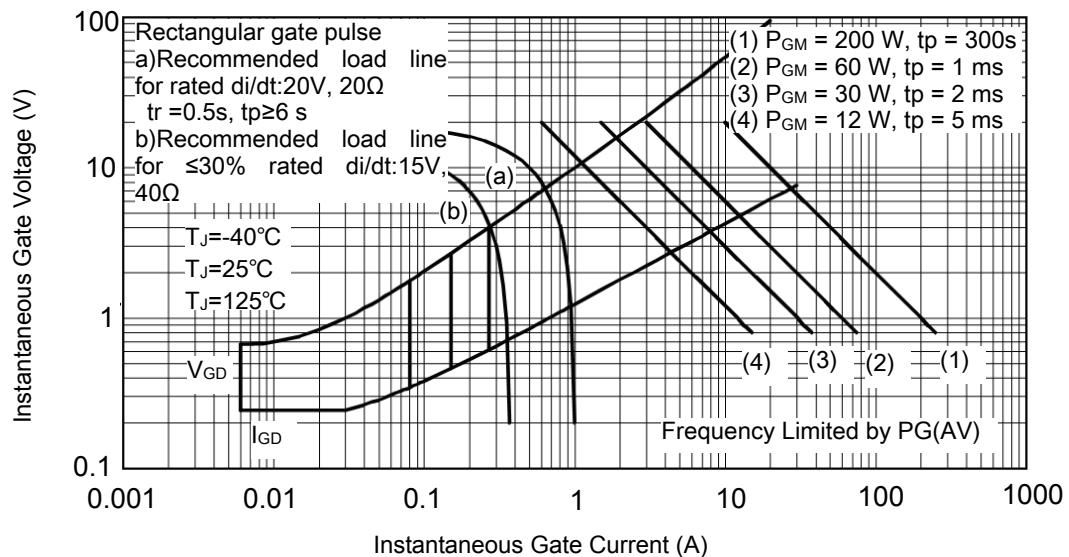


Figure 7. Gate Characteristics

**Package Outline (Dimensions in mm)**